

54F/74F190 Up/Down Decade Counter with Preset and Ripple Clock

General Description

The 'F190 is a reversible BCD (8421) decade counter featuring synchronous counting and asynchronous presetting. The preset feature allows the 'F190 to be used in programmable dividers. The Count Enable input, the Terminal Count output and the Ripple Clock output make possible a variety of methods of implementing multistage counters. In the counting modes, state changes are initiated by the rising edge of the clock.

Features

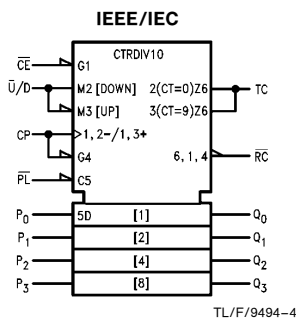
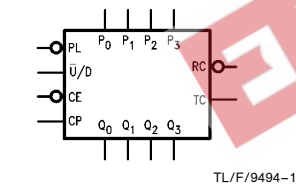
- High-speed—125 MHz typical count frequency
- Synchronous counting
- Asynchronous parallel load
- Cascadable

Commercial	Military	Package Number	Package Description
74F190PC		N16E	16-Lead (0.300" Wide) Molded Dual-In-Line
	54F190DM (Note 2)	J16A	16-Lead Ceramic Dual-In-Line
74F190SC (Note 1)		M16A	16-Lead (0.150" Wide) Molded Small Outline, JEDEC
	54F190FM (Note 2)	W16A	16-Lead Cerpack
	54F190LM (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

Note 1: Devices also available in 13" reel. Use suffix = SCX.

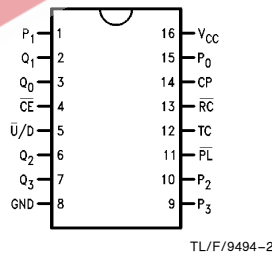
Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMOB and LMQB.

Logic Symbols

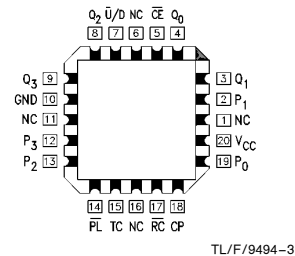


Connection Diagrams

Pin Assignment for
DIP, SOIC and Flatpak



Pin Assignment
for LCC



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Unit Loading/Fan Out



Pin Names	Description	54F/74F	
		U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
\overline{CE}	Count Enable Input (Active LOW)	1.0/3.0	20 μ A/ -1.8 mA
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	20 μ A/ -0.6 mA
P_0 - P_3	Parallel Data Inputs	1.0/1.0	20 μ A/ -0.6 mA
\overline{PL}	Asynchronous Parallel Load Input (Active LOW)	1.0/1.0	20 μ A/ -0.6 mA
$\overline{U/D}$	Up/Down Count Control Input	1.0/1.0	20 μ A/ -0.6 mA
Q_0 - Q_3	Flip-Flop Outputs	50/33.3	-1 mA/20 mA
\overline{RC}	Ripple Clock Output (Active LOW)	50/33.3	-1 mA/20 mA
TC	Terminal Count Output (Active HIGH)	50/33.3	-1 mA/20 mA

Functional Description



The 'F190 is a synchronous up/down BCD decade counter containing four edge-triggered flip-flops, with internal gating and steering logic to provide individual preset, count-up and count-down operations. It has an asynchronous parallel load capability permitting the counter to be preset to any desired number. When the Parallel Load (\overline{PL}) input is LOW, information present on the Parallel Data inputs (P_0 - P_3) is loaded into the counter and appears on the Q outputs. This operation overrides the counting functions, as indicated in the Mode Select Table. A HIGH signal on the \overline{CE} input inhibits counting. When \overline{CE} is LOW, internal state changes are initiated synchronously by the LOW-to-HIGH transition of the clock input. The direction of counting is determined by the $\overline{U/D}$ input signal, as indicated in the Mode Select Table, \overline{CE} and $\overline{U/D}$ can be changed with the clock in either state, provided only that the recommended setup and hold times are observed.



Two types of outputs are provided as overflow/underflow indicators. The Terminal Count (TC) output is normally LOW and goes HIGH when a circuit reaches zero in the count-down mode or reaches 9 in the count-up mode. The TC output will then remain HIGH until a state change occurs, whether by counting or presetting or until $\overline{U/D}$ is changed. The TC output should not be used as a clock signal because it is subject to decoding spikes. The TC signal is also used internally to enable the Ripple Clock (\overline{RC}) output. The \overline{RC} output is normally HIGH. When \overline{CE} is LOW and TC is HIGH, the \overline{RC} output will go LOW when the clock next goes LOW and will stay LOW until the clock goes HIGH again. This feature simplifies the design of multistage counters. For a discussion and illustrations of the various methods of implementing multistage counters, please see the 'F191 data sheet.

\overline{RC} Truth Table

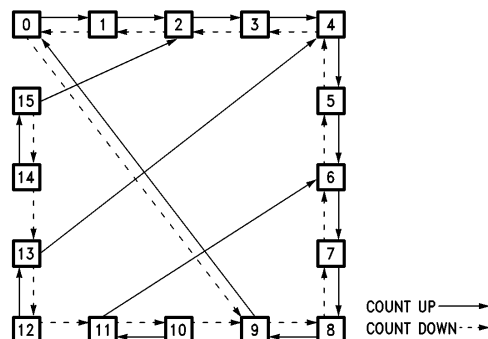
Inputs			Output
\overline{CE}	TC*	CP	\overline{RC}
L	H		
H	X	X	H
X	L	X	H

Mode Select Table

Inputs				Mode
\overline{PL}	\overline{CE}	$\overline{U/D}$	CP	
H	L	L		Count Up
H	L	H		Count Down
L	X	X	X	Preset (Asyn.)
H	H	X	X	No Change (Hold)

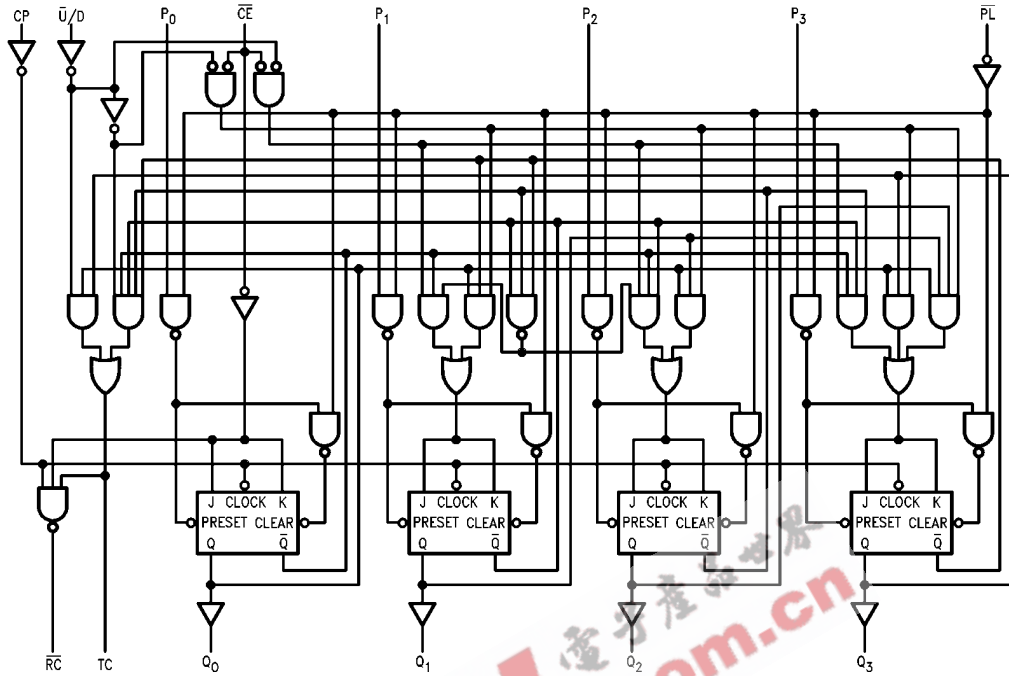
*TC is generated internally
H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
 = LOW-to-HIGH Clock Transition
 = LOW Pulse

State Diagram



TL/F/9494-5

Logic Diagram



TL/F/9494-6

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature	-65°C to +150°C
Ambient Temperature under Bias	-55°C to +125°C
Junction Temperature under Bias	-55°C to +175°C
Plastic	-55°C to +150°C
V _{CC} Pin Potential to Ground Pin	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to +7.0V
Input Current (Note 2)	-30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V _{CC} = 0V)	
Standard Output	-0.5V to V _{CC}
TRI-STATE® Output	-0.5V to +5.5V

Current Applied to Output in LOW State (Max) twice the rated I_{OL} (mA)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	-55°C to +125°C
Commercial	0°C to +70°C
Supply Voltage	
Military	+4.5V to +5.5V
Commercial	+4.5V to +5.5V

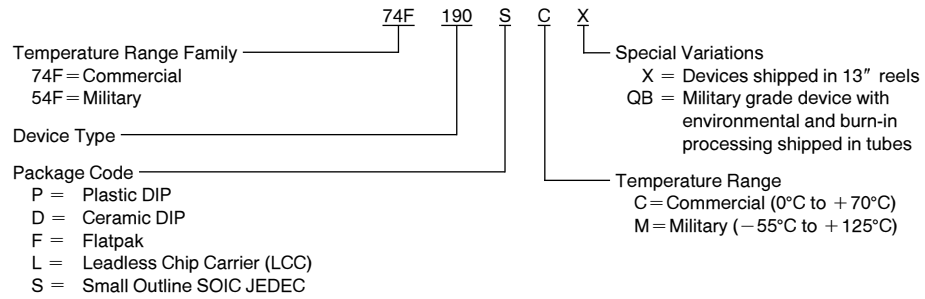
DC Electrical Characteristics

Symbol	Parameter	54F/74F			Units	V _{CC}	Conditions
		Min	Typ	Max			
V _{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V _{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V _{CD}	Input Clamp Diode Voltage			-1.2	V	Min	I _{IN} = -18 mA
V _{OH}	Output HIGH Voltage	54F 10% V _{CC} 74F 10% V _{CC} 74F 5% V _{CC}	2.5 2.5 2.7		V	Min	I _{OH} = -1 mA I _{OH} = -1 mA I _{OH} = -1 mA
V _{OL}	Output LOW Voltage	54F 10% V _{CC} 74F 10% V _{CC}		0.5 0.5	V	Min	I _{OL} = 20 mA I _{OL} = 20 mA
I _{IH}	Input HIGH Current	54F 74F		20.0 5.0	μA	Max	V _{IN} = 2.7V
I _{BVI}	Input HIGH Current Breakdown Test	54F 74F		100 7.0	μA	Max	V _{IN} = 7.0V
I _{CEX}	Output HIGH Leakage Current	54F 74F		250 50	μA	Max	V _{OUT} = V _{CC}
V _{ID}	Input Leakage Test	74F	4.75		V	0.0	I _{ID} = 1.9 μA All Other Pins Grounded
I _{OD}	Output Leakage Circuit Current	74F		3.75	μA	0.0	V _{IOD} = 150 mV All Other Pins Grounded
I _{IL}	Input LOW Current			-0.6 -1.8	mA	Max	V _{IN} = 0.5V, except \overline{CE} V _{IN} = 0.5V, CE
I _{OS}	Output Short-Circuit Current		-60	-150	mA	Max	V _{OUT} = 0V
I _{CCL}	Power Supply Current		38	55	mA	Max	V _O = LOW

AC Electrical Characteristics									
Symbol	Parameter	74F			54F		74F		Units
		T _A = +25°C V _{CC} = +5.0V C _L = 50 pF			T _A , V _{CC} = Mil C _L = 50 pF		T _A , V _{CC} = Com C _L = 50 pF		
		Min	Typ	Max	Min	Max	Min	Max	
f _{max}	Maximum Clock Frequency	100	125		75		90		MHz
t _{PLH} t _{PHL}	Propagation Delay CP to Q _n	3.0 5.0	5.5 8.5	7.5 11.0	3.0 5.0	9.5 13.5	3.0 5.0	8.5 12.0	ns
t _{PLH} t _{PHL}	Propagation Delay CP to TC	6.0 5.0	10.0 8.5	13.0 11.0	6.0 5.0	16.5 13.5	6.0 5.0	14.0 12.0	
t _{PLH} t _{PHL}	Propagation Delay CP to \overline{RC}	3.0 3.0	5.5 5.0	7.5 7.0	3.0 3.0	9.5 9.0	3.0 3.0	8.5 8.0	ns
t _{PLH} t _{PHL}	Propagation Delay \overline{CE} to \overline{RC}	3.0 3.0	5.0 5.5	7.0 7.0	3.0 3.0	9.0 9.0	3.0 3.0	8.0 8.0	
t _{PLH} t _{PHL}	Propagation Delay $\overline{U/D}$ to \overline{RC}	7.0 5.5	11.0 9.0	18.0 12.0	7.0 5.5	22.0 14.0	7.0 5.5	20.0 13.0	ns
t _{PLH} t _{PHL}	Propagation Delay $\overline{U/D}$ to \overline{TC}	4.0 4.0	7.0 6.5	10.0 10.0	4.0 4.0	13.5 12.5	4.0 4.0	11.0 11.0	
t _{PLH} t _{PHL}	Propagation Delay P _n to Q _n	3.0 6.0	4.5 10.0	7.0 13.0	3.0 6.0	9.0 16.0	3.0 6.0	8.0 14.0	ns
t _{PLH} t _{PHL}	Propagation Delay \overline{PL} to Q _n	5.0 5.5	8.5 9.0	11.0 12.0	5.0 5.5	13.0 14.5	5.0 5.5	12.0 13.0	
AC Operating Requirements									
Symbol	Parameter	74F		54F		74F		Units	
		T _A = +25°C V _{CC} = +5.0V		T _A , V _{CC} = Mil		T _A , V _{CC} = Com			
		Min	Max	Min	Max	Min	Max		
t _s (H) t _s (L)	Setup Time, HIGH or LOW P _n to \overline{PL}	4.5 4.5		6.0 6.0		5.0 5.0		ns	
t _h (H) t _h (L)	Hold Time, HIGH or LOW P _n to \overline{PL}	2.0 2.0		2.0 2.0		2.0 2.0			
t _s (L)	Setup Time, LOW \overline{CE} to CP	10.0		10.5		10.0		ns	
t _h (L)	Hold Time, LOW \overline{CE} to CP	0		0		0			
t _s (H) t _s (L)	Setup Time, HIGH or LOW $\overline{U/D}$ to CP	12.0 12.0		12.0 12.0		12.0 12.0		ns	
t _h (H) t _h (L)	Hold Time, HIGH or LOW $\overline{U/D}$ to CP	0 0		0 0		0 0			
t _w (L)	\overline{PL} Pulse Width, LOW	6.0		8.5		6.0		ns	
t _w (L)	CP Pulse Width, LOW	5.0		7.0		5.0		ns	
t _{rec}	Recovery Time \overline{PL} to CP	6.0		7.5		6.0		ns	

Ordering Information

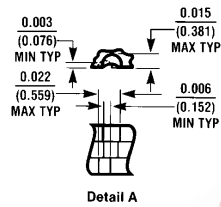
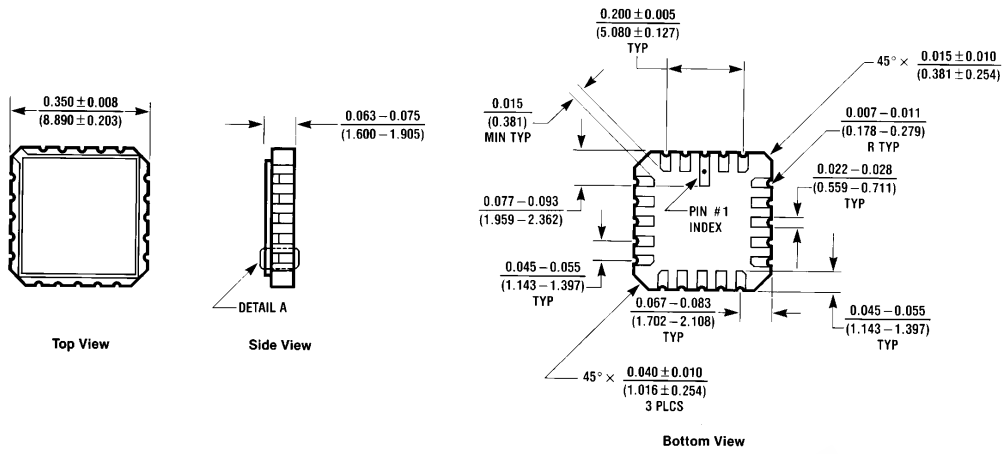
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



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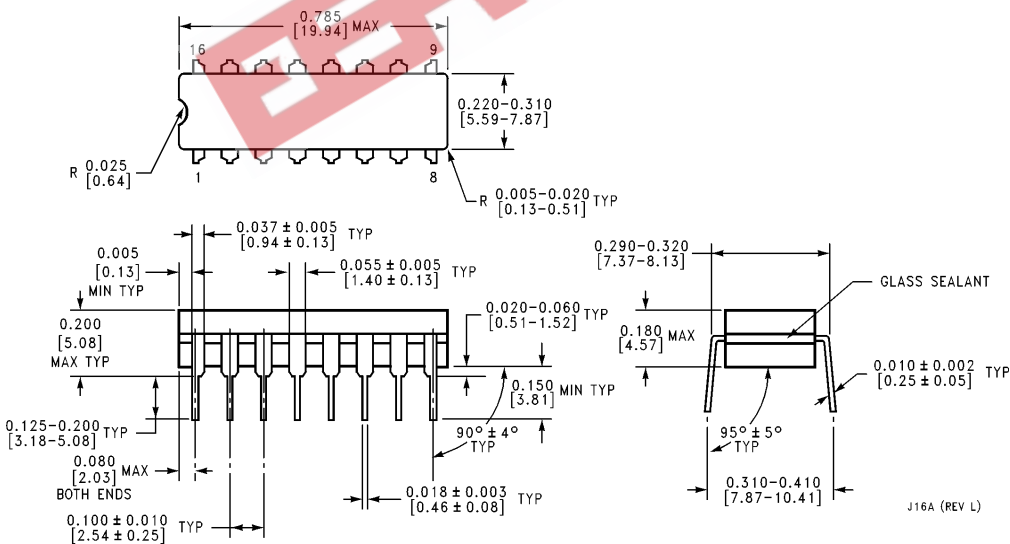
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Physical Dimensions inches (millimeters)



20-Lead Ceramic Leadless Chip Carrier (L)
 NS Package Number E20A

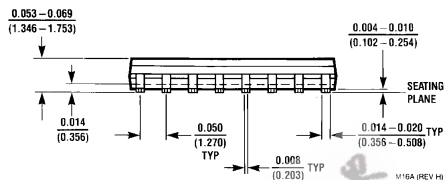
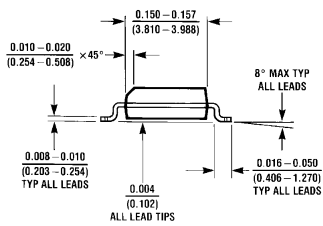
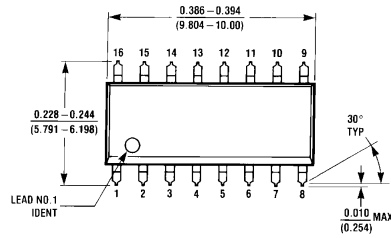
E20A (REV D)



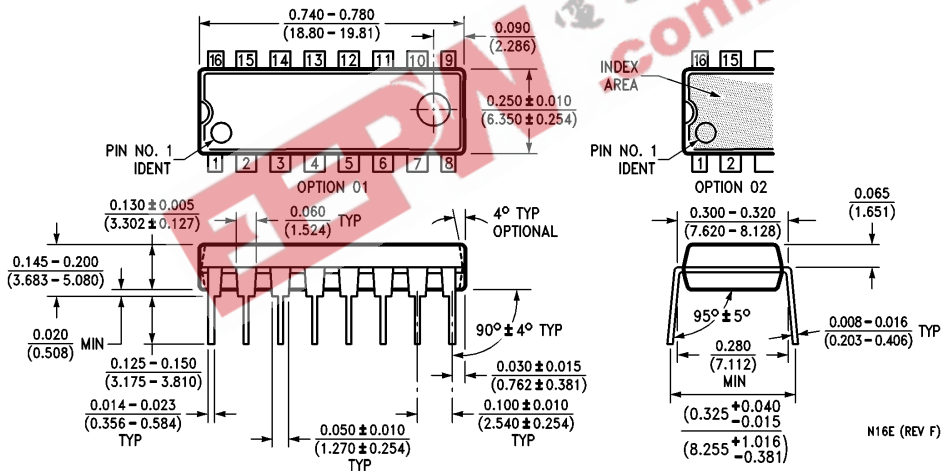
16-Lead Ceramic Dual-In-Line Package (D)
 NS Package Number J16A

J16A (REV L)

Physical Dimensions inches (millimeters) (Continued)

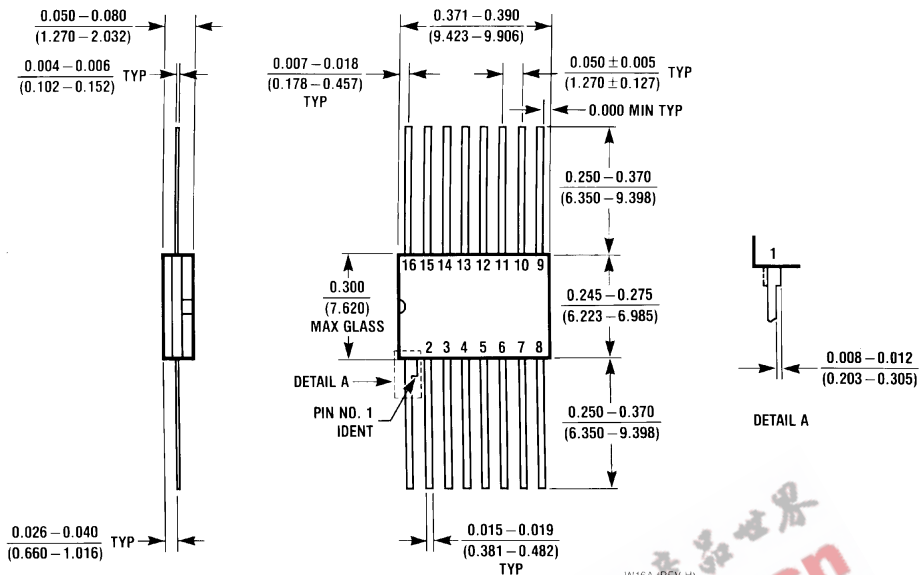


16-Lead (0.150" Wide) Molded Small Outline Package, JEDEC (S)
NS Package Number M16A



16-Lead (0.300" Wide) Molded Dual-In-Line Package (P)
NS Package Number N16E

Physical Dimensions inches (millimeters) (Continued)



**16-Lead Ceramic Flatpak (F)
NS Package Number W16A**

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